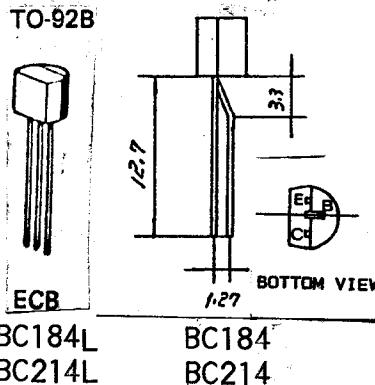


ME

BC184 BC184L BC214 BC214L

COMPLEMENTARY SILICON AF SMALL SIGNAL AMPLIFIERS & DRIVERS

The BC184, BC184L (NPN) and BC214, BC214L (PNP) are complementary silicon planar epitaxial transistors for use in AF small signal amplifiers and drivers, as well as for low noise pre-amplifiers applications. Both types feature good linearity of DC current gain.



BC184L
BC214L

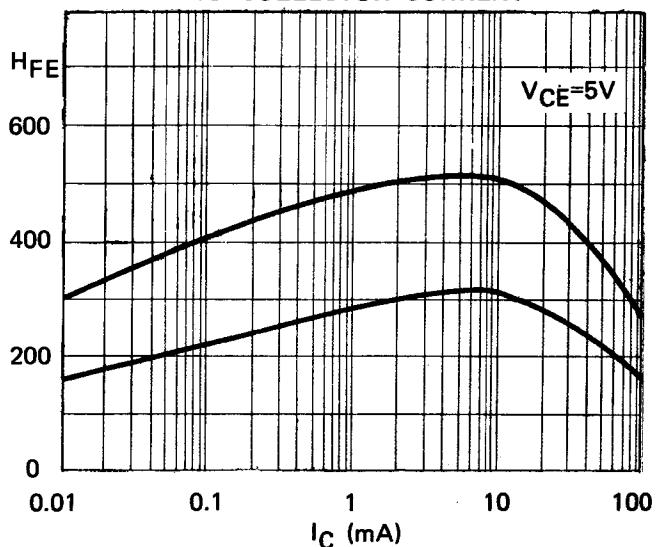
BC184
BC214

ABSOLUTE MAXIMUM RATINGS

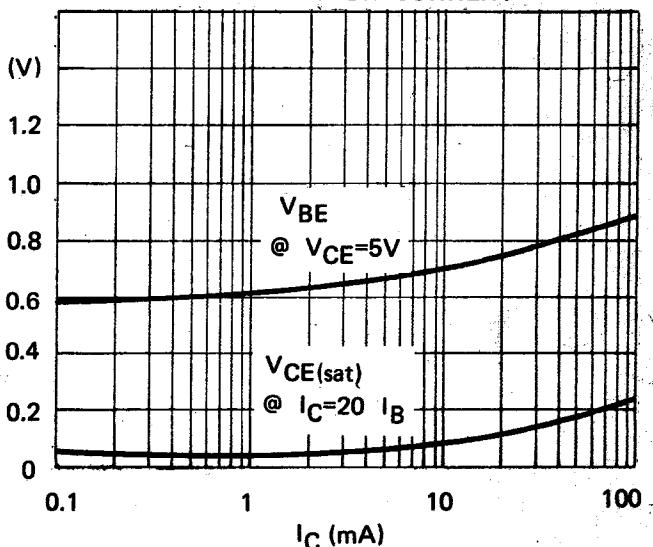
	<u>BC184,L</u>	<u>BC214,L</u>
Collector-Base Voltage	V _{CBO} 45V	45V
Collector-Emitter Voltage	V _{CEO} 30V	30V
Emitter-Base Voltage	V _{EBO} 6V	5V
Collector Current	I _C 200mA	
Total Power Dissipation @ T _A =25°C Derate above 25°C	P _{tot} 300mW 2.4mW/°C	
Operating Junction and Storage Temperature	T _j , T _{stg} -55 to +150°C	

TYPICAL CHARACTERISTICS (T_A=25°C unless otherwise specified)

D.C. CURRENT GAIN
vs COLLECTOR CURRENT



V_{BE} AND V_{CE(sat)}
vs COLLECTOR CURRENT



MICRO ELECTRONICS LTD.

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ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise specified)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	TEST CONDITIONS
Collector-Emitter Breakdown Voltage	BV_{CEO}	30			V	$I_C=2\text{mA}$ $I_B=0$
Collector-Base Breakdown Voltage	BV_{CBO}	45			V	$I_C=10\mu\text{A}$ $I_E=0$
Emitter-Base Breakdown Voltage BC184,L BC214,L	BV_{EBO}	6 5			V	$I_E=10\mu\text{A}$ $I_C=0$
Collector Cutoff Current	ICBO		15	nA		$\text{V}_{\text{CB}}=30\text{V}$ $I_E=0$
Emitter Cutoff Current	IEBO		15	nA		$\text{V}_{\text{EB}}=4\text{V}$ $I_C=0$
Collector-Emitter Saturation BC184,L BC214,L	$\text{V}_{\text{CE}}(\text{sat})$		0.25 0.07 0.6	V		$I_C=10\text{mA}$ $I_B=0.5\text{mA}$ $I_C=100\text{mA}$ $I_B=5\text{mA}^*$
Base-Emitter Saturation BC184,L BC214,L	$\text{V}_{\text{BE}}(\text{sat})$		1.2 1.1	V		$I_C=100\text{mA}$ $I_B=5\text{mA}^*$
Base-Emitter Voltage BC184,L BC214,L	V_{BE}	0.55 0.6	0.7 0.72	V		$\text{V}_{\text{CE}}=5\text{V}$ $I_C=2\text{mA}$
D.C. Current Gain BC184,L BC214,L BC184,L BC214,L	HFE	100 220 140 130 120				$\text{V}_{\text{CE}}=5\text{V}$ $I_C=10\mu\text{A}$ $\text{V}_{\text{CE}}=5\text{V}$ $I_C=2\text{mA}$ $\text{V}_{\text{CE}}=5\text{V}$ $I_C=100\text{mA}^*$
Small Signal Current Gain ($f=1\text{KHz}$) BC184,L BC214,L Group B Group C	h_{fe}	240 140 240 450	900 500 900			$\text{V}_{\text{CE}}=5\text{V}$ $I_C=2\text{mA}$
Output Capacitance BC184,L BC214,L	C_{ob}	3 5	pF			$\text{V}_{\text{CB}}=10\text{V}$ $I_E=0$ $f=1\text{MHz}$
Input Capacitance BC184,L	C_{ib}	9.5	pF			$\text{V}_{\text{EB}}=0.5\text{V}$ $I_E=0$ $f=1\text{MHz}$
Current Gain-Bandwidth Product BC184,L BC214,L	f_T	280 350		MHz		$I_C=10\text{mA}$ $\text{V}_{\text{CE}}=5\text{V}$ $f=100\text{MHz}$
Noise Figure BC184,L BC214,L	NF		4 2	dB		$I_C=200\mu\text{A}$ $\text{V}_{\text{CE}}=5\text{V}$ $R_G=2\text{k}\Omega$ $N=15.7\text{KHz}$ $f_1=10\text{Hz}$ $f_2=10\text{MHz}$

* Pulse Test : Pulse Width = $300\mu\text{s}$, Duty Cycle $\leq 2\%$.